Silicon Carbide Schottky Diode

650 V, 30 A

FFSH3065ADN-F155

Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

Features

- Max Junction Temperature 175°C
- Avalanche Rated 81 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- This Device is Pb–Free, Halogen Free/BFR Free and RoHS Compliant

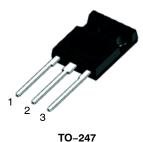
Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

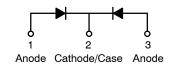


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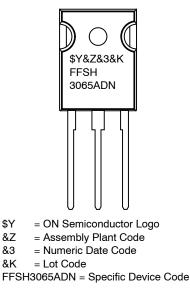
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LONG LEAD CASE 340CH



MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

| Symbol | Parameter | Value | Unit | |
|-----------------------------------|--|--|-------------|-----|
| V _{RRM} | Peak Repetitive Reverse Voltage | 650 | V | |
| E _{AS} | Single Pulse Avalanche Energy (Note 1) | 81 | mJ | |
| ١ _F | Continuous Rectified Forward Current @ T _C < 148°C (Note 2) | | 16*/30** | А |
| | Continuous Rectified Forward Current @ T _C < 135°C | | 23*/36** | |
| I _{F,Max} | Non-Repetitive Peak Forward Surge Current | T _C = 25°C, 10 μs | 1000 | Α |
| | | T _C = 150°C, 10 μs | 900 | Α |
| I _{F,SM} | Non-Repetitive Forward Surge Current | Half-Sine Pulse, t _p = 8.3 ms | 90 | Α |
| I _{F,RM} | Repetitive Forward Surge Current | Half-Sine Pulse, t _p = 8.3 ms | 50 | А |
| Ptot | Power Dissipation | $T_{\rm C} = 25^{\circ}{\rm C}$ | 165 | W |
| | | T _C = 150°C | 28 | W |
| T _J , T _{STG} | Operating and Storage Temperature Range | | -55 to +175 | °C |
| | TO247 Mounting Torque, M3 Screw | | 60 | Ncm |

Table 1. ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. E_{AS} of 81 mJ is based on starting $T_J = 25^{\circ}$ C, L = 0.5 mH, $I_{AS} = 18$ A, V = 50 V.

2. Limited by per device.

Table 2. THERMAL CHARACTERISTICS

| Symbol | Parameter | Rating | Unit |
|-----------------------|--|-------------|------|
| $R_{	extsf{	heta}JC}$ | Thermal Resistance, Junction-to-Case, Max. | 0.91*/0.4** | °C/W |

* Per Leg ** Per Device

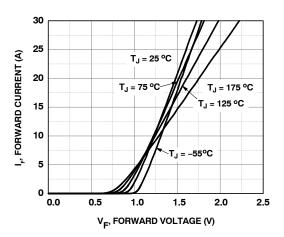
Table 3. OPERATING CHARACTERISTICS (T_C = 25°C, unless otherwise noted)

| Symbol | Parameter | Test Conditions | Min | Тур | Max | Unit |
|----------------|-------------------------|--|-----|------|------|------|
| V _F | Forward Voltage | $I_F = 16 \text{ A}, \text{ T}_C = 25^{\circ}\text{C}$ | - | 1.5 | 1.75 | V |
| | | $I_F = 16 \text{ A}, T_C = 125^{\circ}\text{C}$ | - | 1.6 | 2.0 | |
| | | $I_F = 16 \text{ A}, \text{ T}_C = 175^{\circ}\text{C}$ | - | 1.72 | 2.4 | |
| I _R | Reverse Current | V_R = 650 V, T_C = 25°C | - | - | 200 | μΑ |
| | | $V_{R} = 650 \text{ V}, \text{ T}_{C} = 125^{\circ}\text{C}$ | - | - | 400 | |
| | | $V_{R} = 650 \text{ V}, \text{ T}_{C} = 175^{\circ}\text{C}$ | - | - | 600 | |
| Q _C | Total Capacitive Charge | V = 400 V | - | 52 | - | nC |
| С | Total Capacitance | V _R = 1 V, f = 100 kHz | - | 887 | - | pF |
| | | V _R = 200 V, f = 100 kHz | - | 95 | - | |
| | | V _R = 400 V, f = 100 kHz | - | 72 | - |] |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

PART MARKING AND ORDERING INFORMATION

| Part Number | Top Mark | Package | Packing Method | Reel Size | Tape Width | Quantity |
|------------------|-------------|------------------|----------------|-----------|------------|----------|
| FFSH3065ADN-F155 | FFSH3065ADN | TO-247 Long Lead | Tube | N/A | N/A | 30 units |



TYPICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)



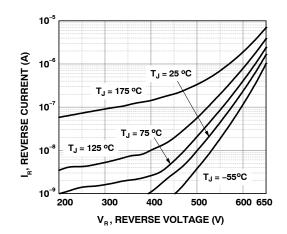
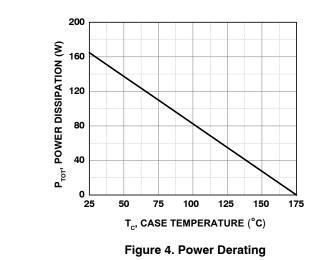


Figure 2. Reverse Characteristics



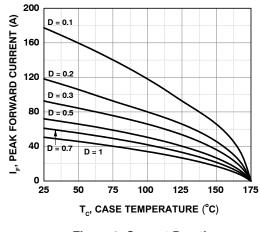


Figure 3. Current Derating

TYPICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

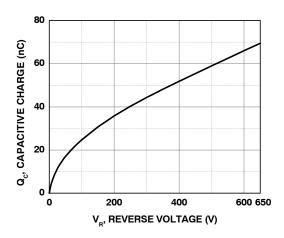


Figure 5. Capacitive Charge vs. Reverse Voltage

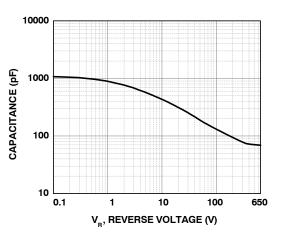


Figure 6. Capacitance vs. Reverse Voltage

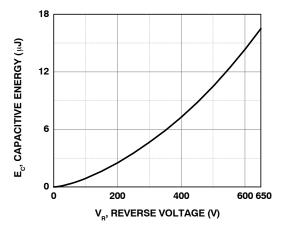


Figure 7. Capacitance Stored Energy

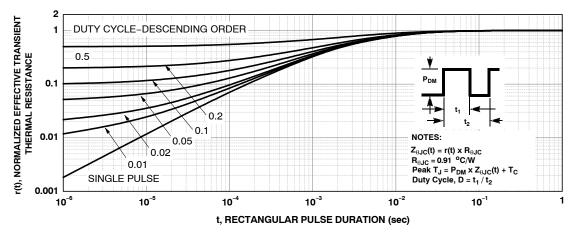


Figure 8. Junction-to-Case Transient Thermal Response Curve

TYPICAL CHARACTERISTICS (T_J = $25^{\circ}C$ unless otherwise noted)

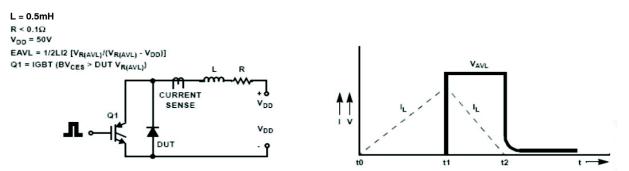
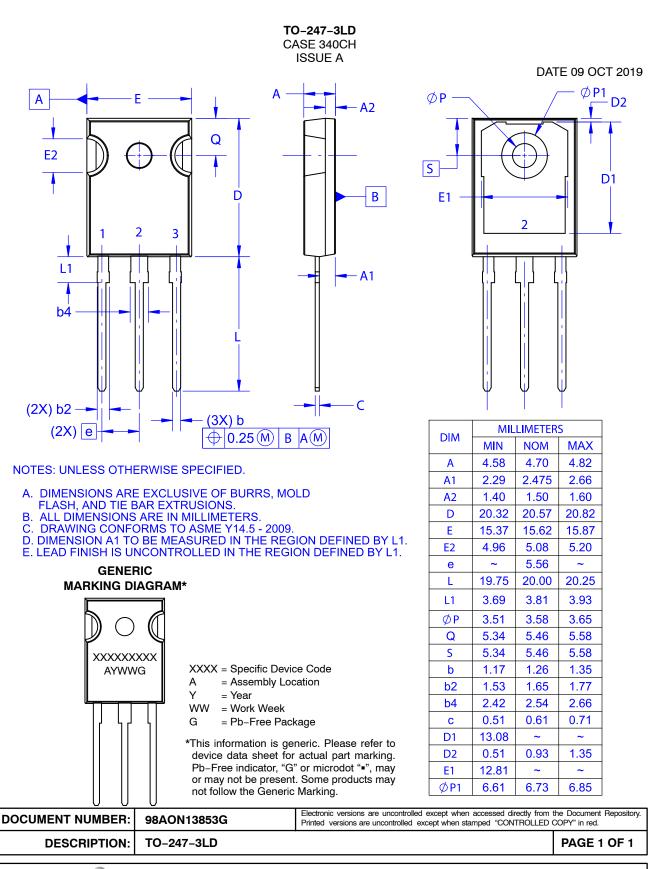


Figure 9. Unclamped Inductive Switching Test Circuit & Waveform





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